



AP7361C

5 OUT

GND

4 IN

1A LOW DROPOUT ADJUSTABLE AND FIXED-MODE REGULATOR WITH ENABLE

Pin Assignments

Description

The AP7361C is a 1A, adjustable and fixed output voltage, ultra-low dropout linear regulator with enable. The device includes pass element, error amplifier, band-gap reference, current limit and thermal shutdown circuitry. The device is turned on when EN pin is set to logic high level.

The characteristics of the low dropout voltage and low quiescent current make it suitable for low-to-medium power applications; for example, laptop computers, audio and video applications, and battery-powered devices. The typical quiescent current is approximately 60µA. Built-in current-limit and thermal-shutdown functions prevent IC from damage in fault conditions.

The AP7361C is available in U-DFN3030-8 (Type E), SOT89-5, SOT223, TO252 (DPAK) and SO-8EP packages.

Features

- Wide Input Voltage Range: 2.2V to 6.0V
- Output Voltage Accuracy: ±1%
- Very Low Dropout Voltage (3.3V): 360mV at 1A Typical
- Low Quiescent Current (IQ): 60µA Typical
- Adjustable Output Voltage Range: 0.8V to 5.0V
- Fixed Output Options: 1.0V, 1.2V, 1.5V, 1.8V, 2.5V, 2.8V and • 3 31/
- High PSRR: 75dB @ 1kHz
- Current Limit: 1.5A .
- Fold-Back Short Circuit Protection: 400mA •
- **Thermal Shutdown Protection** •
- Stable with MLCC, E-Cap, Tan-Cap or Solid Capacitor ≥ 2.2µF •
- Ambient Temperature Range: -40°C to +85°C
- Available in "Green" Molding Compound (No Br, Sb)
- Moisture Sensitivity: Level 1 Per J-STD-020
- Terminals:
 - SOT89-5/ SOT223/ SO-8EP/ TO252: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 @3)
 - U-DFN3030-8: Finish - NiPdAu over Copper Leads, Solderable per MIL-STD-202, Method 208 @4)
- Weight:
 - U-DFN3030-8: 0.017 grams (Approximate)
 - SOT89-5: 0.059 grams (Approximate)
 - SOT223: 0.113 grams (Approximate)
 - SO-8EP: 0.081 grams (Approximate)
 - TO252: 0.33 grams (Approximate)
- Diodes automotive grade parts (Q-suffix) are suitable for automotive applications requiring specific change control; these parts are AEC-Q100/101/200 qualified, PPAP capable, and manufactured in IATF16949:2016 certified facilities. https://www.diodes.com/quality/product-definitions/
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)







SOT223

SOT223R



(Top View)





(Top View)



SO-8EPR



Applications

- LCD-TV, Monitor
- Set-Top-Box
- Home Electrical Appliances

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Vout

Typical Applications Circuit





 V_{IN}

Fixed Version with EN



Fixed Version without EN

Pin Descriptions

			Pin Num	nber				Pin	
U-DFN3030-8 (Type E)	SOT89-5	TO252 (DPAK)	TO252 (DPAK)R	SOT223	SOT223R	SO-8EP	SO-8EPR	Name	Function
8	4	1	3	1	3	8	8	IN	The input of the regulator. Bypass to ground through at least 1µF ceramic capacitor.
1	5	3	2	3	2	1	1	OUT	The output of the regulator. Bypass to ground through at least 2.2µF ceramic capacitor. For improved ac load response a larger capacitor is recommended.
4	2	2	1	2	1	4	3	GND	Ground
3	3	_	_	_	_	_	2	ADJ/NC	Adjustable voltage version only – a resistor divider from this pin to the OUT pin and ground sets the output voltage.
5	1	-	-	-	-	2	5	EN	Enable input, active high
2, 6, 7	-	-	-	-	-	3, 5, 6, 7	4, 6, 7	NC	No connection



Functional Block Diagram





Fixed Version without EN



Symbol	Parameter		Rating	Unit	
V _{IN}	Input Voltage		6.5	V	
-	OUT, ADJ, EN Voltage		V _{IN} +0.3	V	
TJ	Operating Junction Temperature Range	e	-40 to +150	°C	
T _{STG}	Storage Temperature Range		-65 to +150	°C	
P _D	Power Dissipation		Internally limited by maximum junction temperature of +150°C		
		U-DFN3030-8 (Type E)	1700		
		TO252 (DPAK)	1250		
PD	Power Dissipation	SOT223	1100	mW	
		SOT89-5	800		
		SO-8EP	1190		
ESD HBM	Human Body Model ESD Protection	Human Body Model ESD Protection		KV	
ESD MM	Machine Model ESD Protection (Note 5	Machine Model ESD Protection (Note 5)		V	

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.) (Note 4)

Notes: 4. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

5. ESD MM rating at 150V for EN pin in SOT89-5 package.

Recommended Operating Conditions (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Мах	Unit
VIN	Input Voltage	2.2	6.0	V
Vout	Output Voltage	0.8	5.0	V
IOUT	Output Current (Note 6)	0	1.0	A
T _A	Operating Ambient Temperature	-40	+85	°C

Notes: 6. The device maintains a stable, regulated output voltage without a load current. When the output current is large, attention should be given to the limitation of the package power dissipation.



Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
VREF	FB Reference Voltage, ADJ pin	I _{OUT} = 10mA, T _A = +25°C	;	0.792	0.8	0.808	V
I _{ADJ}	ADJ Pin Leakage Current	-		-	0.1	0.5	μA
lq	Input Quiescent Current	Enabled, I _{OUT} = 0A		-	60	80	μA
I _{SHDN}	Input Shutdown Current	$V_{EN} = 0V, I_{OUT} = 0A$		-1	0.05	1	μA
V _{OUT} C		I _{OUT} = 100mA,	1.0V≤V _{OUT} <1.5V	V _{OUT} (s)- 0.015	V _{OUT} (s)	V _{OUT} (s)+ 0.015	
Vout	Output Voltage Accuracy	T _A = +25°C	1.5 V≤V _{OUT} ≤3.3V	V _{OUT} (s)* 0.99	V _{OUT} (s)	V _{OUT} (s)* 1.01	- V
ΔVουτ		$V_{IN} = V_{OUT} + 1V$ to 5.5V,	T _A = +25°C	-	0.01	0.1	0/ //
$\Delta V_{\text{IN}} \times V_{\text{OUT}}$	Line Regulation	$I_{OUT} = 100 \text{mA}$	-40°C ≤T _A ≤ +85°C	-	-	0.2	%/V
ΔV _{OUT} / V _{OUT}	Load Regulation	I _{OUT} from 1.0mA to 1A	1.2V <v<sub>OUT≤ 3.3V</v<sub>	-1.0	_	1.0	%
			1.0V ⊡ V _{OUT} ≤1.2V	-1.5	-	1.5	%
			1.0V≤V _{OUT} <1.1V	_	710	750	
			1.1V≤V _{OUT} <1.2V	-	600	640]
	Dropout Voltage (Note 7)		1.2V≤V _{OUT} <1.3V	-	500	540	
		I _{OUT} = 300mA	1.3V≤V _{OUT} <1.4V	-	400	440	- - - - - -
			1.4V≤V _{OUT} <1.5V	-	300	340	
			1.5V≤V _{OUT} <2.6V	-	200	250	
			2.6V≤V _{OUT} ≤3.3V	-	90	140	
Vdropout		I _{OUT} = 1A	1.0V≤V _{OUT} <1.1V	-	840	_	
			1.1V≤V _{OUT} <1.2V	-	780	-	
			1.2V≤V _{OUT} <1.3V	_	710	-	
			1.3V≤V _{OUT} <1.4V	_	660	-	
			1.4V≤V _{OUT} <1.5V	_	610	-	
			1.5V≤V _{OUT} <2.0V	-	570	_	
			2.0V≤V _{OUT} <2.6V	-	440	-	
			2.6V≤V _{OUT} ≤3.3V	_	340	_	
VIL	EN Input Logic Low Voltage	-		0	_	0.3	V
VIH	EN Input Logic High Voltage	-		1.0	-	VIN	V
R _{ENPD}	EN Pull-Down Resistor	-		-	3.0	-	MΩ
I _{EN}	EN Input Leakage Current	$V_{IN} = 5.5V, V_{EN} = 0V$		-0.1	_	0.1	μA
R _{PD}	Output Discharge Resistor	V _{OL} =1V		-	100	-	Ω
IOUT	Maximum Output Current	V _{IN} = V _{OUT} +1V		1.0	_	-	Α
ILIMIT	Current Limit	$V_{IN} = V_{OUT} + 1V(V_{IN MINI} =$	2.2V)	1.1	1.5	-	Α
I _{SHORT}	Short-Circuit Current	$V_{IN} = V_{OUT} + 1V$, Output Voltage < 15% V_{OUT}		-	400	-	mA
	Power Supply Rejection Ratio	$f = 1$ kHz, $I_{OUT} = 100$ mA		-	75	-	.15
PSRR	(Note 8)	$f = 10kHz$, $I_{OUT} = 100mA$		-	55	-	dB
ts⊤	Start-Up Time	$V_{OUT} = 3V, C_{OUT} = 2.2\mu F, R_L = 30\Omega$		-	150	-	μs
$\frac{\Delta V_{\text{OUT}}}{\Delta T_{\text{A}} \times V_{\text{OUT}}}$	Output Voltage Temperature Coefficient			_	±100	-	ppm/°
T _{SHDN}	Thermal Shutdown Threshold	-		_	150	-	°C
THYS	Thermal Shutdown Hysteresis			-	20	<u> </u>	°C

$\label{eq:Electrical Characteristics} (@\ T_A = +25^{\circ}C, \ vin = V_{OUT} + 1V, \ C_{IN} = 4.7 \mu F, \ C_{OUT} = 4.7 \mu F, \ V_{EN} = V_{IN}, \ unless \ otherwise \ specified.)$

Notes: 7. Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value. This parameter only applies to output voltages above 1.2V since minimum V_{IN} = 2.2V.

8. For $V_{\text{IN}} \geq$ 2.5V and V_{IN} = V_{OUT} +1V. For V_{IN} < 2.5V, the PSRR performance may be reduced.



Electrical Characteristics (@ $T_A = +25^{\circ}C$, $V_{IN} = V_{OUT} + 1V$, $C_{IN} = 4.7\mu$ F, $C_{OUT} = 4.7\mu$ F, $V_{EN} = V_{IN}$, unless otherwise specified.) (Cont.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
		U-DFN3030-8 (Type E) (Note 9)	-	70	-	
		TO252 (DPAK) (Note 9)	-	95	-	
θ _{JA}	Thermal Resistance Junction-to-	SOT223 (Note 9)	-	110	-	°C/W
		SOT89-5 (Note 9)	-	150	-	
		SO-8EP (Note 9)	-	100	-	

Notes: 9. Test condition: U-DFN3030-8 (Type E), SO-8EP devices are mounted on 2"x2", FR-4 substrate PCB, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane. TO252(DPAK) devices are mounted on 2"x2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. For SOT223, the device is mounted on FR-4 substrate PC board, with minimum recommended pad layout. SOT89-5 devices are mounted on 1"x1" FR-4 substrate PC board, with minimum recommended pad layout.

Performance Characteristics





AP7361C Document number: DS37274 Rev. 5 - 2





Load Transient Response







Time (200µs/div)



Load Transient Response





Time (200µs/div)

Load Transient Response











Input Quiescent Current vs Input Voltage



Input Quiescent Current vs Temperature







Application Information

Input Capacitor

A 1µF ceramic capacitor is recommended between the IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and reduce noise. For PCB layout, a wide copper trace is required for both IN and GND pins. A lower ESR capacitor type allows the use of less capacitance, while higher ESR type requires more capacitance.

Output Capacitor

The output capacitor is required to stabilize and improve the transient response of the LDO. The AP7361C is stable with very small ceramic output capacitors. Using a ceramic capacitor value that is at least 2.2µF on the output ensures stability. Higher capacitance values help to improve line and load transient response. The output capacitance may be increased to keep low undershoot and overshoot. Output capacitor must be placed as close as possible to OUT and GND pins.



Application Information (Cont.)

Adjustable Operation

The AP7361C provides output voltage from 0.8V to 5.0V through external resistor divider as shown below.



Adjustable Output

The output voltage is calculated by:

$$\mathbf{V}_{\rm OUT} = \mathbf{V}_{\rm REF} \left(1 + \frac{\mathbf{R}_1}{\mathbf{R}_2} \right)$$

Where V_{REF} = 0.8V (the internal reference voltage)

Rearranging the equation will give the following that is used for adjusting the output to a particular voltage:

$$R1 = R2 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

To maintain the stability of the internal reference voltage, R2 needs to be kept smaller than 80kΩ.

No Load Stability

Other than external resistor divider, no minimum load is required to keep the device stable. The device will remain stable and regulated in no load condition.

ON/OFF Input Operation

The ON/OFF feature is not available in the SOT223 and TO252 (DPAK) packages.

The AP7361C is turned on by setting the EN pin high, and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under V_{IL} and V_{IH} .

Current Limit Protection

When output current at OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to prevent over-current and to protect the regulator from damage due to overheating.

Short Circuit Protection

When OUT pin is short-circuit to GND, short circuit protection will be triggered and clamp the output current to approximately 400mA. Full current is restored when the output voltage exceeds 15% of V_{OUT}. This feature protects the regulator from over-current and damage due to overheating.



Application Information (Cont.)

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +150°C, allowing the device to cool down. When the junction temperature reduces to approximately +130°C the output circuitry is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Ultra Fast Start-up

After enabled, the AP7361C is able to provide full power in as little as tens of microseconds, typically 200µs, without sacrificing low ground current. This feature will help load circuitry move in and out of standby mode in real time, eventually extend battery life for mobile phones and other portable devices.

Low Quiescent Current

The AP7361C, consuming only around 60µA for all input range, provides great power saving in portable and low power applications.

Power Dissipation

The device power dissipation and proper sizing of the thermal plane that is connected to the thermal pad is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

 $P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$

The maximum power dissipation, handled by the device, depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be calculated by the equation in the following:

$$P_{D}(\max@T_{A}) = \frac{(+150^{\circ}C - T_{A})}{R_{\theta JA}}$$

ESR vs. Output Current

Ceramic type output capacitor is recommended for this series; however, the other output capacitors with low ESR also can be used. The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The stable region for the safety operating temperature (-40°C ~ +85°C) is marked as the gray area in the graph.

Measurement conditions: Frequency Band: 10Hz to 2MHz, Temperature: -40°C to +85°C.





Ordering Information



Part Number	Package Code Packaging		7"/13" Tape and Reel		
Fart Number	Fackage Code	Fackaying	Quantity	Part Number Suffix	
AP7361C-XXFGE-7	FGE	U-DFN3030-8 (Type E)	3000/Tape & Reel	-7	
AP7361C-XXY5-13	Y5	SOT89-5	2500/Tape & Reel	-13	
AP7361C-XXD-13	D	TO252 (DPAK)	2500/Tape & Reel	-13	
AP7361C-XXDR-13	DR	TO252 (DPAK)R	2500/Tape & Real	-13	
AP7361C-XXE-13	E	SOT223	2500/Tape & Reel	-13	
AP7361C-XXER-13	ER	SOT223R	2500/Tape & Reel	-13	
AP7361C-XXSP-13	SP	SO-8EP	2500/Tape & Reel	-13	
AP7361C-XXSPR-13	SPR	SO-8EPR	2500/Tape & Reel	-13	



Marking Information

(1) U-DFN3030-8 (Type E)



Device	Package	Identification Code
AP7361C-ADJ	U-DFN3030-8 (Type E)	SH
AP7361C-10	U-DFN3030-8 (Type E)	SJ
AP7361C-12	U-DFN3030-8 (Type E)	SK
AP7361C-15	U-DFN3030-8 (Type E)	SV
AP7361C-18	U-DFN3030-8 (Type E)	SW
AP7361C-25	U-DFN3030-8 (Type E)	SX
AP7361C-28	U-DFN3030-8 (Type E)	SY
AP7361C-33	U-DFN3030-8 (Type E)	SZ

(2) SOT89-5



Device	Package	Identification Code
AP7361C-ADJ	SOT89-5	KR
AP7361C-10	SOT89-5	KS
AP7361C-12	SOT89-5	KT
AP7361C-15	SOT89-5	KU
AP7361C-18	SOT89-5	KV
AP7361C-25	SOT89-5	KW
AP7361C-28	SOT89-5	КХ
AP7361C-33	SOT89-5	KZ



(3) TO252 (DPAK)

Pin 1: IN, Pin 2: GND, Pin 3: OUT



(4) SOT223

Pin 1: IN, Pin 2: GND, Pin 3: OUT



(5) SOT223R

Pin 1: GND, Pin 2: OUT, Pin 3: IN





Marking Information (Cont.)

(6) TO252 (DPAK)R

Pin 1: GND, Pin 2: OUT, Pin 3: IN



(7) SO-8EP

Pin 1: OUT, Pin 2: EN, Pins 3, 5, 6 and 7: NC, Pin 4: GND, Pin 8: IN





Pin 1: OUT, Pin 2: ADJ/NC, Pin 3: GND, Pins 4, 6 and 7: NC, Pin 5: EN, Pin 8: IN





Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: U-DFN3030-8 (Type E)



	U-DFN3030-8						
		pe E					
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0	0.05	0.02				
A3	-	-	0.15				
b	0.20	0.30	0.25				
D	2.95	3.05	3.00				
D2	2.15	2.35	2.25				
Е	2.95	3.05	3.00				
е	-	-	0.65				
E2	1.40	1.60	1.50				
L	0.30	0.60	0.45				
Z	Z – – 0.40						
All I	Dimens	sions ir	n mm				

(2) Package Type: SOT89-5





	SO	Г89-5	
Dim	Min	Max	Тур
Α	1.40	1.60	1.50
в	0.50	0.62	0.56
B1	0.44	0.54	0.48
С	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
Е	2.40	2.60	2.50
е	-	-	1.50
Н	3.95	4.25	4.10
L	0.65	0.95	0.80
All	Dimens	sions in	mm



Package Outline Dimensions (Cont.) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: TO252 (DPAK)



	TO252	(DPA	()
Dim	Min	Max	Тур
Α	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.46	5.33
С	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	-	-
е	-	-	2.286
Ε	6.45	6.70	6.58
E1	4.32	-	-
Н	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
а	0°	10°	-
All	Dimen	sions i	n mm



Package Outline Dimensions (Cont.) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(4) Package Type: SOT223





	- -		
0. e	25-	L	

	SOT223			
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All Dimensions in mm				

(5) Package Type: SO-8EP





SO-8EP			
Dim	Min	Max	Тур
Α	1.40	1.50	1.45
A1	0.00	0.13	1
b	0.30	0.50	0.40
С	0.15	0.25	0.20
D	4.85	4.95	4.90
Е	3.80	3.90	3.85
E0	3.85	3.95	3.90
E1	5.90	6.10	6.00
e	-	-	1.27
F	2.75	3.35	3.05
Н	2.11	2.71	2.41
L	0.62	0.82	0.72
Ν	-	-	0.35
q	0.60	0.70	0.65
All Dimensions in mm			



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: U-DFN3030-8 (Type E)



Dimensions	Value (in mm)
С	0.65
C1	2.35
Х	0.30
Y	0.65
Y1	1.60
Y2	2.75

(2) Package Type: SOT89-5



Dimensions	Value
Dimensions	(in mm)
С	1.500
C1	1.050
Х	0.680
X1	0.760
X2	1.930
X3	3.680
Y	1.200
Y1	1.200
Y2	4.250
Y3	4.500

(3) Package Type: TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



Suggested Pad Layout (Cont.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(4) Package Type: SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

(5) Package Type: SO-8EP



Dimensions	Value (in mm)
С	1.270
Х	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500



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Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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